National Semiconductor

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_M107/LM207/LM307 Operational Amplifiers

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General Description

The LM107 series are complete, general purpose operational amplifiers, with the necessary frequency compensation built into the chip. Advanced processing techniques make the input currents a factor of ten lower than industry standards like the 709. Yet, they are a direct, plug-in replacement for the 709, LM101A and 741.

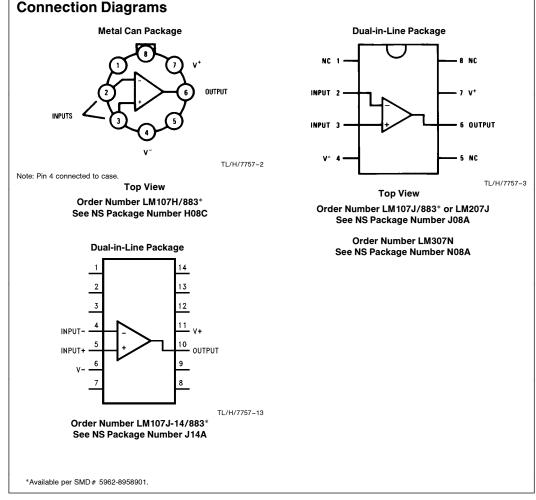
The LM107 series offers the features of the LM101A, which makes its application nearly foolproof. In addition, the device provides better accuracy and lower noise in high impedance circuitry. The low input currents also make it particularly well suited for long integrators or timers, sample and hold circuits and low frequency waveform genera-

tors. Further, replacing circuits where matched transistor pairs buffer the inputs of conventional IC op amps, it can give lower offset voltage and drift at a lower cost.

The LM107 is guaranteed over a $-55^\circ C$ to $+125^\circ C$ temperature range, the LM207 from $-25^\circ C$ to $+85^\circ C$ and the LM307 from 0°C to $+70^\circ C.$

Features

- Offset voltage 3 mV maximum over temperature
- Input current 100 nA maximum over temperature
- Offset current 20 nA maximum over temperature
- Guaranteed drift characteristics



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Absolute Maximum Ratings If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications. (Note 4) LM107/LM207 LM307 Supply Voltage $\pm 18V$ $\pm 22V$ T_{MIN} Тмах Power Dissipation (Note 1) 500 mW 500 mW Differential Input Voltage $\pm 30V$ $\pm 30V$ LM107 -55°C +125°C Input Voltage (Note 2) $\pm 15V$ $\pm\,15V$ LM207 -25°C +85°C Output Short Circuit Duration Continuous Continuous LM307 0°C +70°C Operating Temperature Range (T_A) ESD rating to be determined. (LM107) -55°C to +125°C $0^{\circ}C$ to $+70^{\circ}C$ (LM207) -25°C to +85°C Storage Temperature Range $-65^{\circ}C$ to $+150^{\circ}C$ $-65^{\circ}C$ to $+150^{\circ}C$ 260°C 260°C Lead Temperature (Soldering, 10 sec) **Electrical Characteristics** (Note 3) LM107/LM207 LM307 Parameter Conditions Units Min Тур Max Min Тур Max Input Offset Voltage $T_A = 25^{\circ}C, R_S \le 50 \text{ k}\Omega$ 0.7 2.0 2.0 7.5 mV Input Offset Current $T_A = 25^{\circ}C$ 3.0 50 1.5 10 nA $T_A = 25^{\circ}C$ Input Bias Current 70 30 75 250 nA $T_A = 25^{\circ}C$ Input Resistance 1.5 4.0 0.5 2.0 MΩ $T_A = 25^{\circ}C$ Supply Current $V_{S} = \pm 20V$ 1.8 3.0 mΑ $V_{S} = \pm 15V$ 1.8 3.0 mΑ $T_{A} = 25^{\circ}C, V_{S} = \pm 15V$ Large Signal Voltage 50 160 25 160 V/mV Gain $V_{OUT}=~\pm\,10V,\,R_L\geq 2\,k\Omega$ Input Offset Voltage $R_S \leq 50 \ k\Omega$ 3.0 10 mV Average Temperature Coefficient of Input 3.0 15 6.0 30 μV/°C Offset Voltage Input Offset Current 20 70 nA $25^{\circ}C \leq T_A \leq T_{MAX}$ Average Temperature 0.01 0.1 0.01 0.3 nA/°C Coefficient of Input $T_{MIN} \leq T_A \leq 25^{\circ}C$ 0.02 0.2 0.02 0.6 nA/°C Offset Current Input Bias Current 100 300 nA Supply Current $T_A = +125^{\circ}C, V_S = \pm 20V$ 1.2 2.5 mΑ

Parameter	Conditions	LM107/LM207			LM307			Units
		Min	Тур	Max	Min	Тур	Max	
arge Signal Voltage	$V{S} = \pm 15V, V_{OUT} = \pm 10V$				15			
Gain	$R_L \ge 2 k \Omega$	25						V/m\
Output Voltage Swing	$V_{S} = \pm 15V$							
	$R_{L} = 10 k\Omega$	±12	±14		±12	±14		v
	$R_L = 2 k\Omega$	±10	±13		±10	±13		V
Input Voltage Range	$V_{S} = \pm 20V$	±15						V
	$V_{S} = \pm 15V$		+15		±12	+ 15		v
	_		-13			-13		
Common Mode	${\sf R}_{\sf S} \le$ 50 k Ω				70			10
Rejection Ratio		80	96		70	90		dB
Supply Voltage	$R_S \le 50 \text{ k}\Omega$							
Rejection Ratio	Ŭ	80	96		70	96		dB

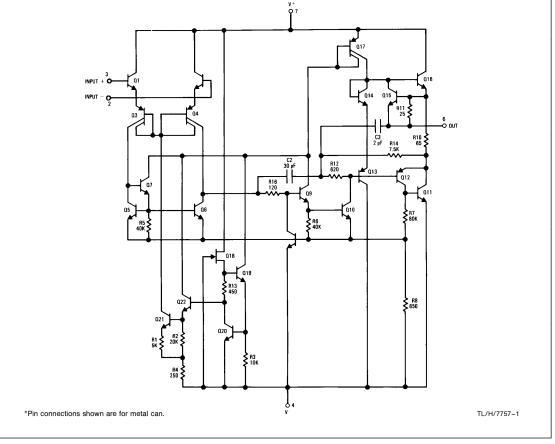
Note 1: The maximum junction temperature of the LM107 is 150°C, and the LM207/LM307 is 100°C. For operating at elevated temperatures, devices in the H08 package must be derated based on a thermal resistance of 165°C/W, junction to ambient, or 30°C/W, junction to case. The thermal resistance of the dual-in-line package is 100°C/W, junction to ambient.

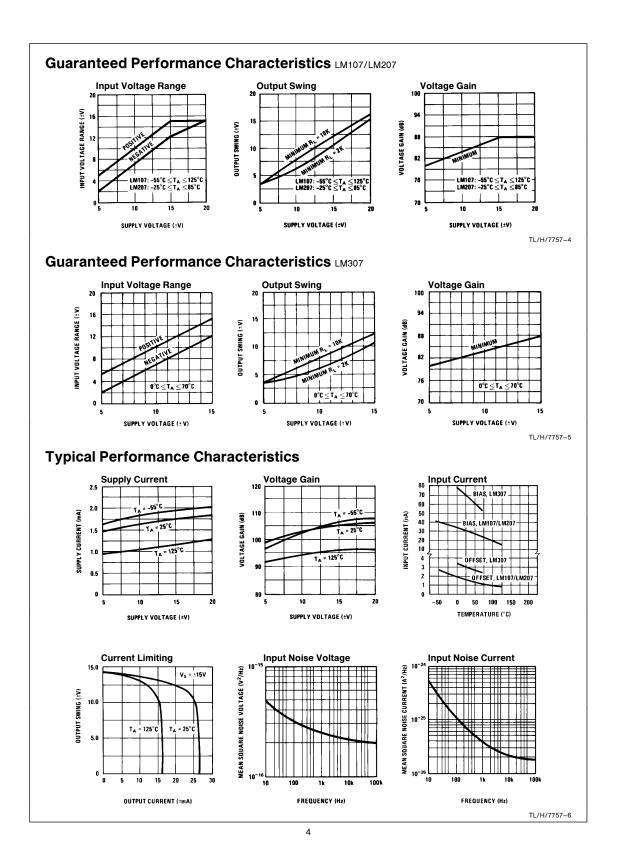
Note 2: For supply voltages less than \pm 15V, the absolute maximum input voltage is equal to the supply voltage.

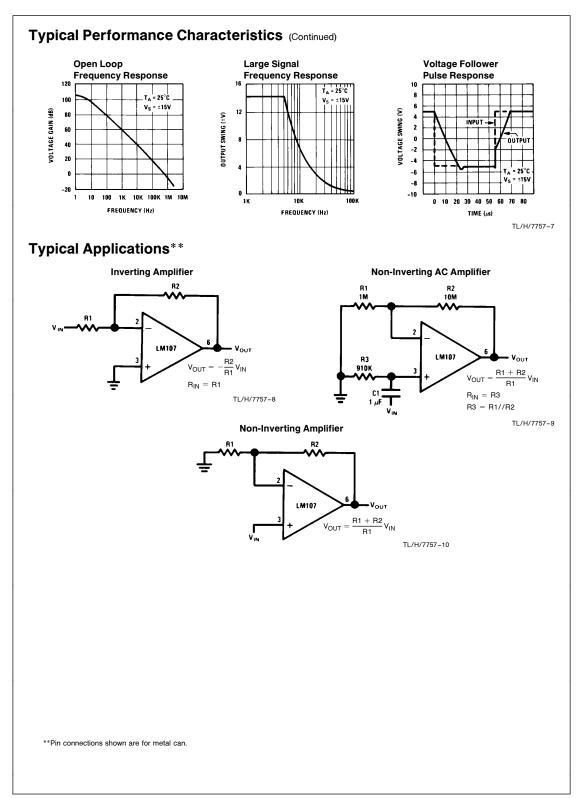
Note 3: These specifications apply for $\pm 5V \le V_S \le \pm 20V$ and $-55^{\circ}C \le T_A \le \pm 125^{\circ}C$ for the LM107 or $-25^{\circ}C \le T_A \pm 85^{\circ}C$ for the LM207, and $0^{\circ}C \le T_A \le \pm 70^{\circ}C$ and $\pm 5V \le V_S \le \pm 15V$ for the LM307 unless otherwise specified.

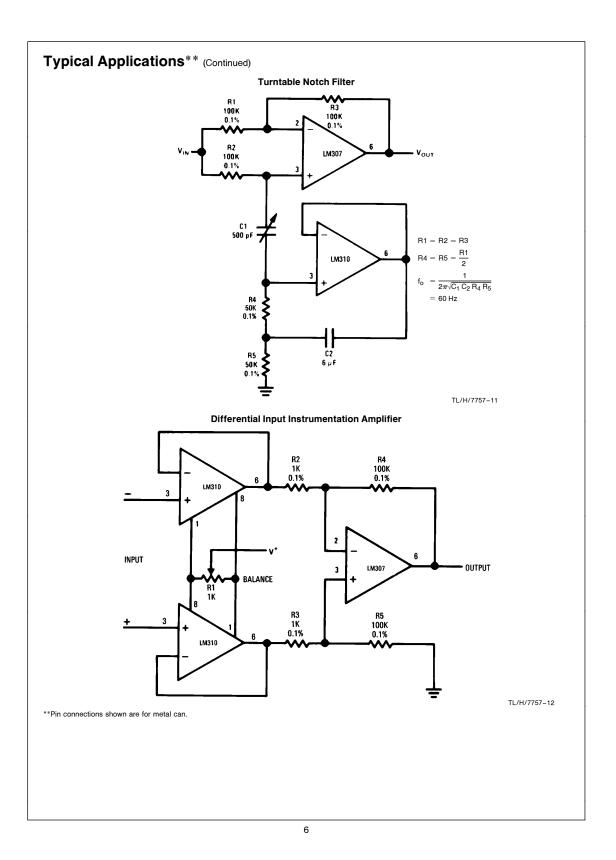
Note 4: Refer to RETS107X for LM107H and LM107J military specifications.

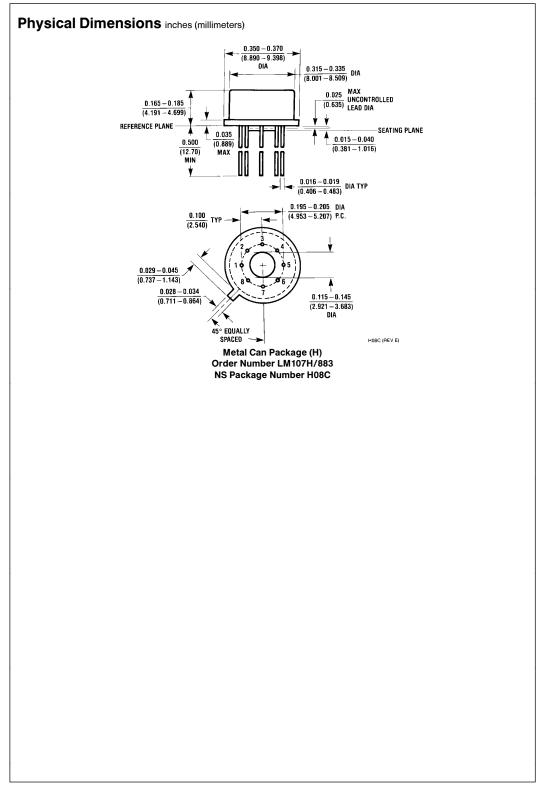
Schematic Diagram*

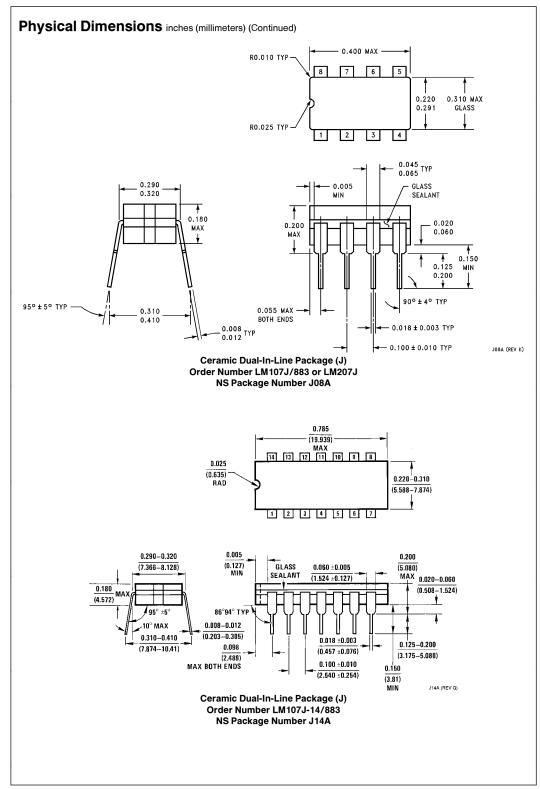


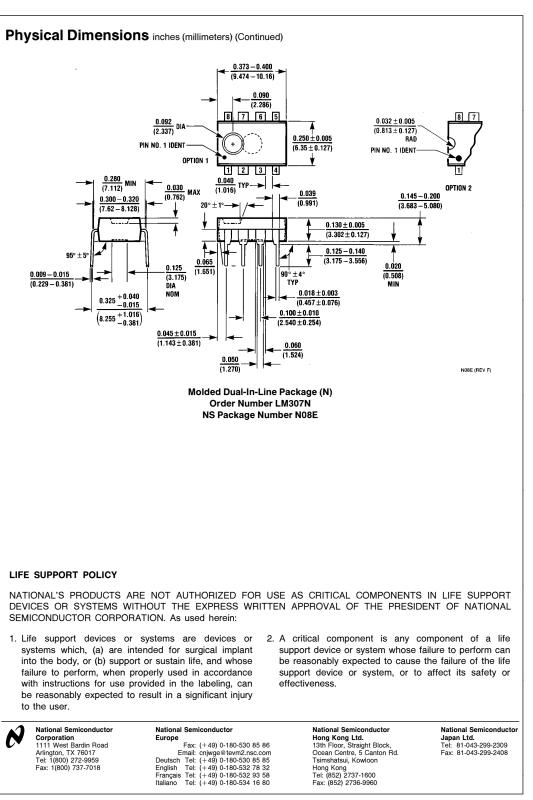












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